TOSHIBA Photocoupler GaAlAs IRed & Photo-IC

TLP113

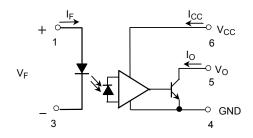
Isolated Line Receiver
Simplex / Multiplex Data Transmission
Computer-Peripheral Interface
Microprocessor System Interface
Digital Isolation For A / D, D / A Conversion

The TOSHIBA mini flat coupler TLP113 is a small outline coupler, suitable for surface mount assembly.

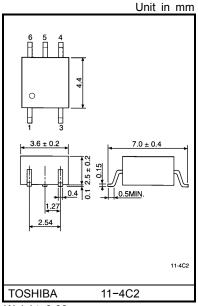
TLP113 consists of a GaA ℓ As light emitting diode, optically coupled to an integrated high gain, high speed photodetector whose output is an open collector, schottky clamped transistor.

- Input current thresholds: IF=10mA(max.)
- Switching speed: 10MBd(typ.)
- TTL / LSTTL compatible: V_{CC}=5V
- Guaranteed performance over temp.: 0~70°C
- Isolation voltage: 2500Vrms(min.)
- UL recognized: UL1577 file no. E67349

Schematic

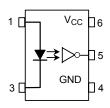


(Note) A 0.1µF bypass capacitor must be connected between pins 4 and 6.



Weight: 0.09g

Pin Configuration(top view)



- 1 : Anode
- 3: Cathode
- 4 : GND
- 5 : Output (Open collector)
- 6: V_{CC}

TRUTH TABLE (Positive Logic)

INPUT	OUTPUT
Н	L
L	Н

Maximum Ratings(Ta = 25°C)

Characteristic			Symbol	Unit	
	Forward current		I _F	20	mA
	Pulse forward current (No	ote 1)	I _{FP}	40	mA
LED	Peak transient forward current (No	ote 2)	I _{FPT}	1	А
	Reverse voltage		V_{R}	5	V
Detector	Output current		ΙO	25	mA
	Output voltage		VO	7	V
	Supply voltage (1 minute maximum)		V _C C	7	V
	Output power dissipation		PO	40	mW
Oper	Operating temperature range		T _{opr}	−40~85	°C
Stora	Storage temperature range		T _{stg}	-55~125	°C
Lead solder temperature (10s)		T _{sol}	260	°C	
Isolation voltage (AC, 1 min., RH ≤ 60%, Note 4)		BVS	V _S 2500		

(Note 1) 50% duty cycle, 1ms pulse width.

(Note 2) Pulse width≤1µs, 300pps.

Recommende Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Input voltage, low level	V _{FL}	-3	0	1.0	V
Input current, high level	I _{FH}	13*	16	20	mA
Supply voltage	V _{CC}	4.5	5	5.5	V
Fan out (TTL load, each channel)	N	_	_	8	_
Operating temperature	T _{opr}	0	_	70	°C

^{* 13}mA is a guard banded value which allows for at least 20% CTR degradation. Initial input current threshold value is 10mA or less.

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Electrical Characteristics(unless otherwise specified, Ta=0~70°C, V_{CC} =4.5~5.5V, V_{FL} ≤ 1.0V)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit	
Forward voltage	V _F	I _F =10mA, Ta=25°C	_	1.65	1.80	V	
Forward voltage temperature coefficient	V _F / Ta	I _F =10mA	_	-2	_	mV / °C	
Reverse current	I _R	V _R =5V, Ta=25°C	_	_	10	μА	
Capacitance between terminals	C _T	V _F =0, f=1MHz, Ta=25°C	_	45	_	pF	
High level output current	lau	V _F =1.0, V _O =5.5V	_	_	250	μΑ	
riigirievei output current	Іон	V _F =1.0, V _O =5.5V, Ta=25°C	_	0.5	10		
Low level output voltage	V _{OL}	I _F =10mA I _{OL} =13mA(sinking)	_	0.4	0.6	٧	
"H level output→ L level output" input current	I _{FH}	I _{OL} =13mA(sinking) V _{OL} =0.6V	_	_	10	mA	
High level supply current	Іссн	V _{CC} =5.5V, I _F =0	_	7	15	mA	
Low level supply current	I _{CCL}	V _{CC} =5.5V, I _F =16mA	_	12	18	mA	
Input-output insulation leakage current	Is	V _S =3540V, t=5s Ta=25°C (Note 4)	_	_	100	μА	
Isolation resistance	RS	R.H. ≤ 60%, V _S =500V DC Ta=25°C (Note 4)	5×10 ¹⁰	10 ¹⁴	_	Ω	
Stray capacitance between input to output	CS	V_S =0, f=1MHz Ta=25°C (Note 4)		0.8	_	pF	

^{*} All typical values are V_{CC} =5V, Ta=25°C

Switching Characteristics (V_{CC}=5V, Ta=25°C)

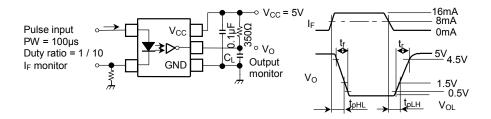
Characteristic	Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit
Propagation delay time (H→L)	t _p HL	1	I_F =0 \rightarrow 16mA C_L =15pF, R_L =350 Ω	_	60	120	ns
Propagation delay time (L→H)	t _p LH	1	I_F =16 \rightarrow 0mA C_L =15pF, R_L =350 Ω	_	60	120	ns
Output rise-fall time (10-90%)	t _r , t _f	2	R _L =350 Ω , C _L =15pF I _F =0 \rightleftharpoons 16mA	_	30	_	ns
Common mode transient imunity at high output level	CM _H	2	I _F =0mA, V _{CM} =200V _{p-p} V _{O(min)} =2V, R _L =350Ω	_	200	_	V / μs
Common mode transient imunity at low output level	CML	2	I_F =16mA, V_{CM} =200 V_{p-p} $V_{O(max)}$ =0.8 V , R_L =350 Ω	_	-500	_	V / μs

⁽Note 4) Device considered a two-terminal device: Pins 1 and 3 shorted together, and pins 4, 5 and 6 shorted together.

(Note 6) Maximum electrostatic discharge voltage for any pins: 180V(C=200pF, R=0)

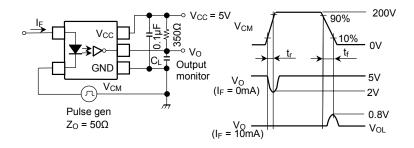
⁽Note 5) The V_{CC} supply voltage to each TLP113 isolator must be bypassed by $0.1\mu F$ capacitor, this can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to package V_{CC} and GND pins of each device.

Test Circuit 1: Switching Time Test Circuit



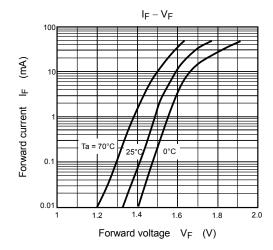
C_L is approximately 15pF which includes probe and stray wiring capacitance.

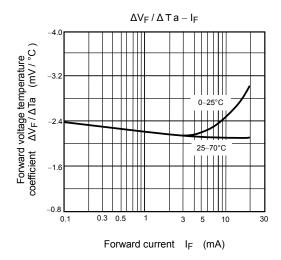
Test Circuit 2: Common Mode Transient Immunity Test Circuit

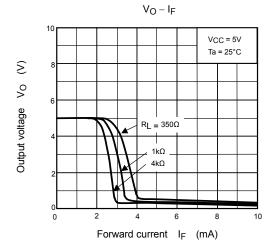


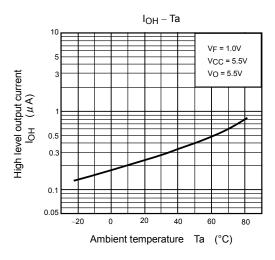
$$CM_H = \frac{160(V)}{t_{\Gamma}(\mu s)}, CM_L = \frac{160(V)}{t_{\Gamma}(\mu s)}$$

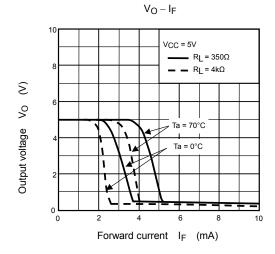
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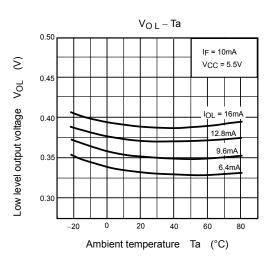




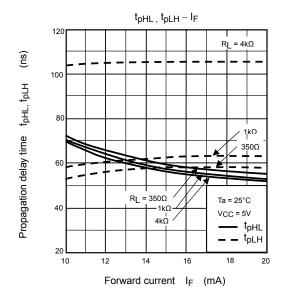


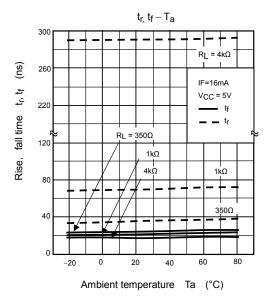


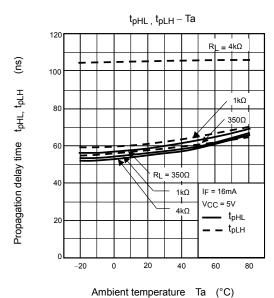




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